

## isc Silicon NPN Power Transistor

# 2SC1913

#### **DESCRIPTION**

- Collector-Emitter Breakdown Voltage-:V<sub>(BR)CEO</sub>= 150(V)(Min.)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

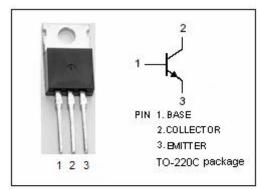
# 0

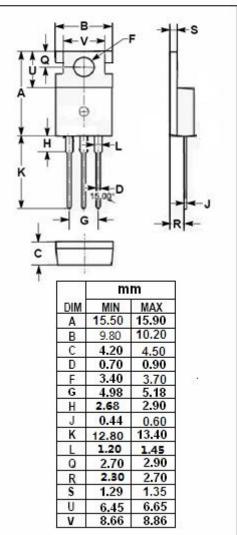
#### **APPLICATIONS**

Designed for audio frequency high power driver

## ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>СВО</sub>	Collector-Base Voltage	150	٧
V <sub>CEO</sub>	Collector-Emitter Voltage	150	٧
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
Ic	Collector Current-Continuous	1.0	А
Pc	Total Power Dissipation @ T <sub>C</sub> =25℃	15	W
TJ	Junction Temperature	150	$^{\circ}$
T <sub>stg</sub>	Storage Temperature Range	-55~150	$^{\circ}$ C







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### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 30mA; I <sub>B</sub> = 0	150			V
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 500mA; I <sub>B</sub> = 30mA			1.0	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 500mA; I <sub>B</sub> = 30mA			1.5	V
Ісво	Collector Cutoff Current	V <sub>CB</sub> = 120V; I <sub>E</sub> = 0			1	uA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 4V; I <sub>C</sub> = 0			1	uA
h <sub>FE-1</sub>	DC Current Gain	Ic= 150mA; V <sub>CE</sub> = 10V	65		330	
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = 500mA; V <sub>CE</sub> = 5V	50			
f⊤	Current-Gain—Bandwidth Product	I <sub>E</sub> = 50mA; V <sub>CE</sub> = 10V		120		MHz

### ♦ h<sub>FE-1</sub> Classifications

Р	Q	R	s
65-110	90-155	130-220	185-330

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